

60V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- $BV_{CEO} > -60V$
- $BV_{ECO} > -7V$
- $I_C = 5A$ High Continuous Current
- Low Saturation Voltage $V_{CE(sat)} < -80mV @ 1A$
- $R_{CE(sat)} = 50m\Omega$
- Complementary PNP Type: ZXTN19060CG
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

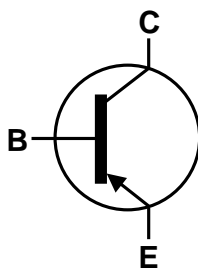
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

Applications

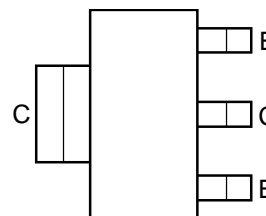
- Motor Drive
- High Side Driver



Top View



Device Symbol



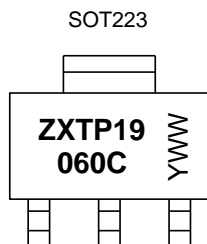
Top View
Pin-Out

Ordering Information (Note 4)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|------------|------------|--------------------|-----------------|-------------------|
| ZXTP19060CGTA | AEC-Q101 | ZXTP19060C | 7 | 12 | 1,000 |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZXTP19060C = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -60 | V |
| Collector-Emitter Voltage | V _{CEO} | -60 | V |
| Emitter-Collector Voltage (reverse blocking) | V _{ECX} | -7 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | I _C | -5 | A |
| Base Current | I _B | -1 | A |
| Peak Pulse Current | I _{CM} | -7 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

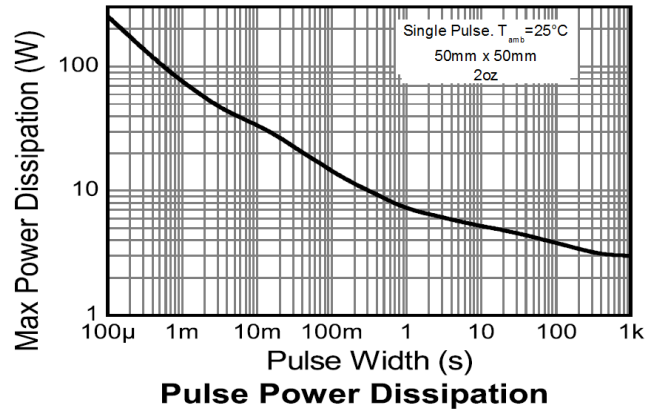
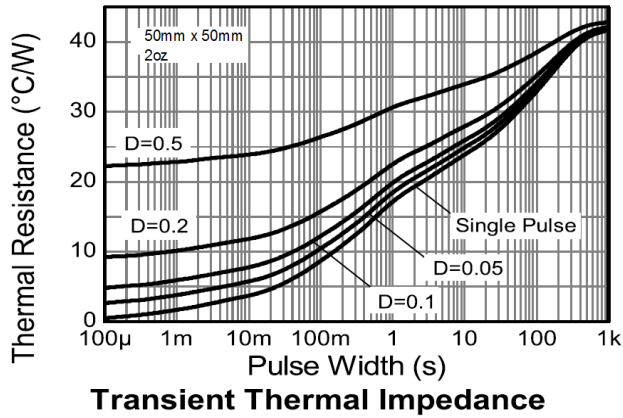
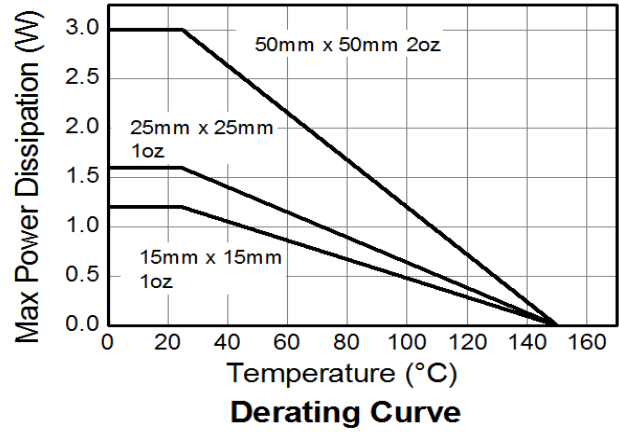
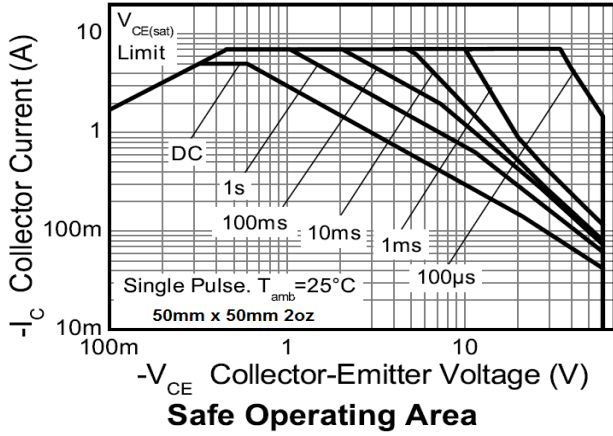
| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------------|
| Power Dissipation Linear Derating Factor | P _D | 1.2 | W mW/°C |
| | | 9.6 | |
| | | 1.6 | |
| | | 12.8 | |
| | | 3 | |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 24 | °C/W |
| | | 5.3 | |
| | | 42 | |
| | | 104 | |
| Thermal Resistance, Junction to Lead | R _{θJL} | 78 | °C/W |
| | | 42 | |
| | | 23.5 | |
| Thermal Resistance, Junction to Lead | (Note 9) | 16 | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 10)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
- For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 - Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
 - Same as Note 6, except the device is mounted on 50mm x 50mm 2oz copper.
 - Same as Note 8 measured at t<5 seconds.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

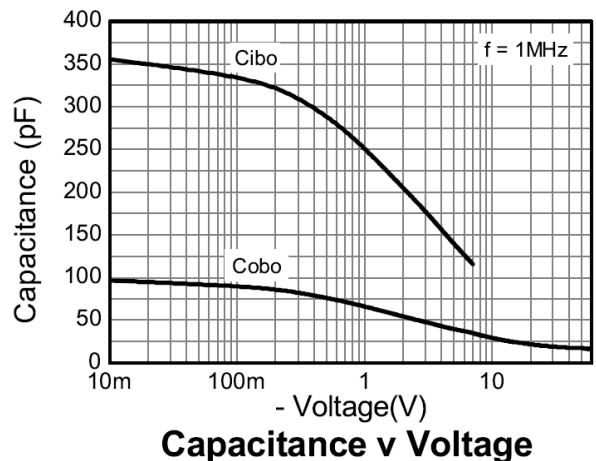
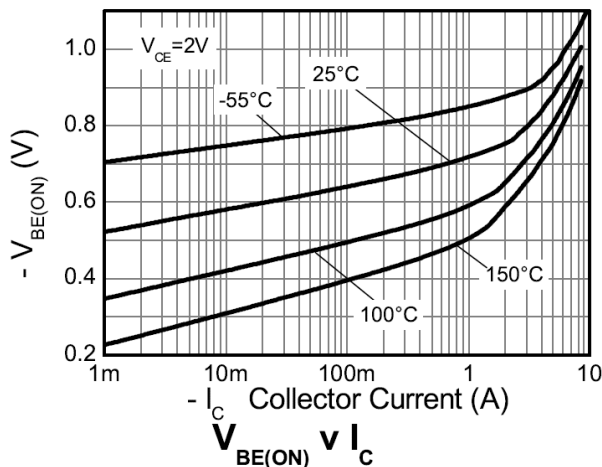
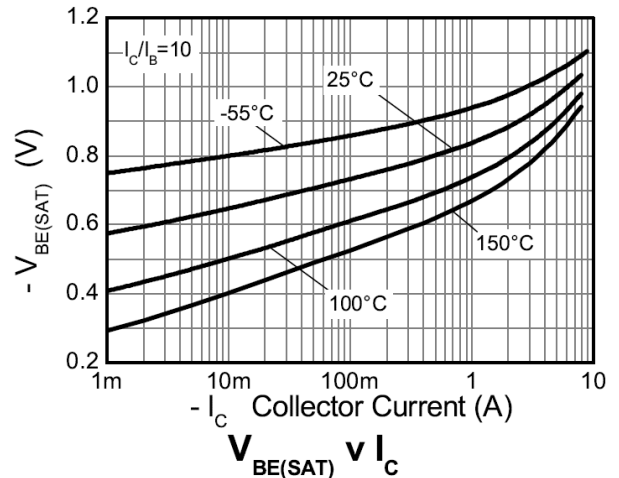
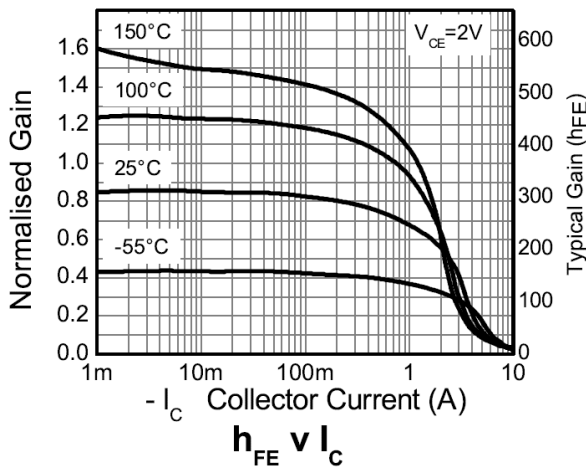
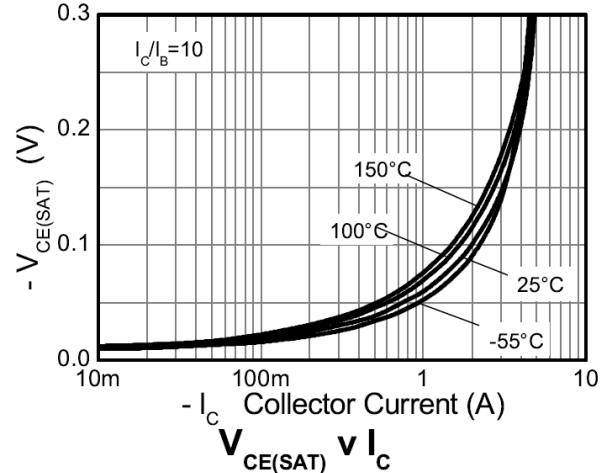
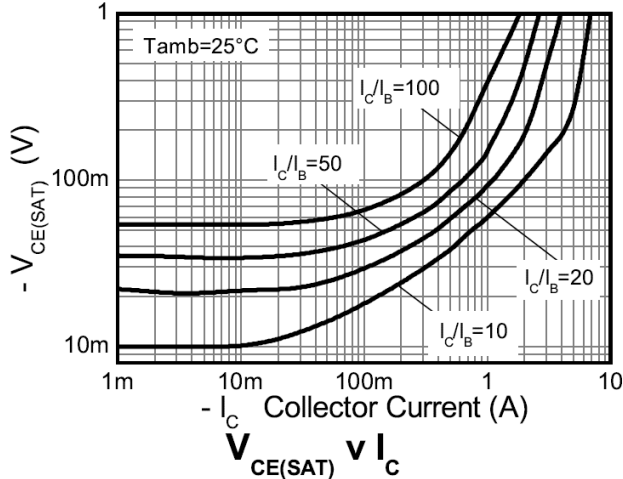


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|-----|------|-------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | -60 | -110 | - | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 11) | BV _{CEO} | -60 | -90 | - | V | I _C = -10mA |
| Emitter-Collector Breakdown Voltage (reverse blocking) | BV _{ECX} | -7 | -8.4 | - | V | I _C = -100μA, R _{BC} <1kΩ or 0.25V < V _{BC} > -0.25V |
| Emitter-Collector Breakdown Voltage (reverse blocking) | BV _{ECO} | -7 | -8.8 | - | V | I _E = -100μA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.4 | - | V | I _E = -100μA |
| Collector Cut-Off Current | I _{CBO} | - | < 1 | -50 | nA | V _{CB} = -60V |
| | | - | - | -0.5 | μA | V _{CB} = -60V, T _A = +100°C |
| Emitter Cut-Off Current | I _{EBO} | - | < 1 | -50 | nA | V _{EB} = -5.6V |
| Collector-Emitter Saturation Voltage (Note 11) | V _{CE(sat)} | - | -62 | -80 | mV | I _C = -1A, I _B = -100mA |
| | | - | -145 | -205 | mV | I _C = -1A, I _B = -20mA |
| | | - | -500 | -750 | mV | I _C = -2A, I _B = -40mA |
| | | - | -105 | -165 | mV | I _C = -2A, I _B = -200mA |
| | | - | -145 | -200 | mV | I _C = -3A, I _B = -300mA |
| | | - | -300 | -500 | mV | I _C = -5A, I _B = -500mA |
| Base-Emitter Saturation Voltage (Note 11) | V _{BE(sat)} | - | -975 | -1050 | mV | I _C = -5A, I _B = -500mA |
| Base-Emitter Turn-On Voltage (Note 11) | V _{BE(on)} | - | -890 | -1000 | mV | I _C = -5A, V _{CE} = -2V |
| DC Current Gain (Note 11) | h _{FE} | 200 | 330 | 500 | - | I _C = -100mA, V _{CE} = -2V |
| | | 160 | 260 | - | - | I _C = -1A, V _{CE} = -2V |
| | | 20 | 40 | - | - | I _C = -5A, V _{CE} = -2V |
| Current Gain-Bandwidth Product (Note 11) | f _T | - | 180 | - | MHz | V _{CE} = -10V, I _C = -50mA, f = 50MHz |
| Input Capacitance (Note 11) | C _{ibo} | - | 280 | 400 | pF | V _{EB} = -0.5V, f = 1MHz |
| Output Capacitance (Note 11) | C _{obo} | - | 29.5 | 40 | pF | V _{CB} = -10V, f = 1MHz |
| Delay Time | t _d | - | 24.3 | - | ns | I _C = -500mA, V _{CC} = -10V, I _{B1} = -I _{B2} = -50mA |
| Rise Time | t _r | - | 13.2 | - | ns | |
| Storage Time | t _s | - | 456 | - | ns | |
| Fall Time | t _f | - | 68.2 | - | ns | |

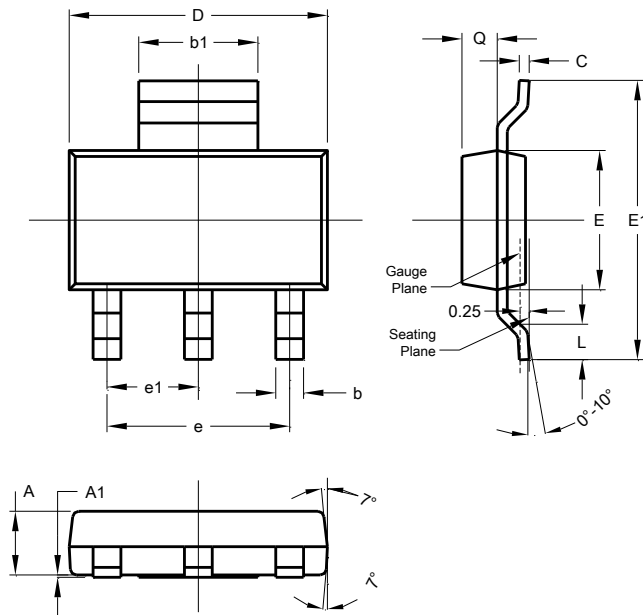
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Package Outline Dimensions

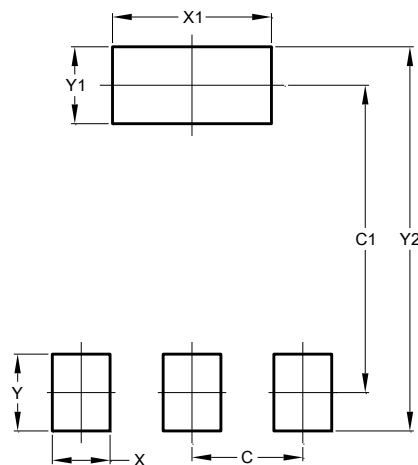
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT223 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 1.55 | 1.65 | 1.60 |
| A1 | 0.010 | 0.15 | 0.05 |
| b | 0.60 | 0.80 | 0.70 |
| b1 | 2.90 | 3.10 | 3.00 |
| C | 0.20 | 0.30 | 0.25 |
| D | 6.45 | 6.55 | 6.50 |
| E | 3.45 | 3.55 | 3.50 |
| E1 | 6.90 | 7.10 | 7.00 |
| e | - | - | 4.60 |
| e1 | - | - | 2.30 |
| L | 0.85 | 1.05 | 0.95 |
| Q | 0.84 | 0.94 | 0.89 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 2.30 |
| C1 | 6.40 |
| X | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |

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